#### Lect. 5: Semicondutors (Razavi 2.1)

What is a semiconductor?



Group IV elements (for example, Si) has four valence electrons

(Also for combination of Group III and Group V elements: for example GaAs)

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How does it look? Diamond-like crystal structure



- Si atoms share electrons with neighboring atoms
- → each atom can have 8 electrons



At finite temperature, some electrons escape from bonds creating mobile electrons and holes



n (density of electrons) = p (density of holes) =  $n_i(T)$  :

 $\rightarrow$  Current conduction due to electrons and holes.

Intrinsic semicondutor

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How much currents flow?



Semiconductor as a resistor!

$$I = \frac{V}{R}$$

$$R = \frac{L}{A\sigma} (\sigma: \text{ conductivity})$$

$$\sigma = \mu \cdot \text{charge density} (\mu: \text{ mobility})$$

$$\text{charge density} = qn + qp$$

$$\sigma = \mu_n qn + \mu_p qp$$

$$R = \frac{L}{Aq(\mu_n n + \mu_p p)}$$

$$I = \frac{V}{L} Aq(\mu_n n + \mu_p p)$$

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What happens when Group V (donor) atoms are added (doping)?



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How much currents flow in N-type semiconductor?



 $I = \frac{V}{R}$  $R = \frac{L}{A\sigma} \ (\sigma: \text{ conductivity})$  $\sigma = \mu \bullet$  charge density ( $\mu$ : mobility) charge density = qn + qp $\sigma = \mu_n qn + \mu_p qp$  $R = \frac{L}{Aq(\mu_n n + \mu_p p)}$  $R \simeq \frac{L}{Aq\mu_n n}$ 

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What happens when Group III (acceptor) atoms are added (doping)?



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How much currents flow in P-type semiconductor?





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Homework Problems (Due Next Monday before Tutorial)

- 1. Determine the conductivity  $\sigma$  of intrinsic Si in ( $\Omega$ cm) <sup>-1</sup>. Use q=1.6 x10<sup>-19</sup> C, n<sub>i</sub>=10<sup>10</sup>/cm<sup>3</sup>,  $\mu$ <sub>n</sub>=1000 cm<sup>2</sup>/Vs,  $\mu$ <sub>p</sub>=400 cm<sup>2</sup>/Vs
- 2. Determine the conductivity  $\sigma$  of extrinsic Si with  $N_D$  = 10^{18}/cm^3 .
- 3. Determine L required for 1K Ohm resistor using the above extrinsic Si. Use A = 100  $\mu m^2$  .



